MSKSEMI 美森科













ESD

TSS

MOV

GDT

PIFD

AZC099-04S-MS

Product specification





Features

- 100 watts peak pulse power per line (t_P=8/20µs)
- Protects four I/O lines
- Low clamping voltage
- Low operating voltage
- Low capacitance
- RoHS compliant

PROTECTION SOLUTION TO MEET

- IEC61000-4-2 (ESD) ±20kV (air), ±20kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 5A (8/20µs)

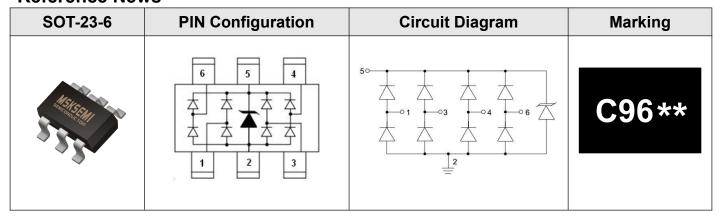
Mechanical Characteristics

- USB 2.0&3.0 power and data line protection
- Digital video interface (DVI)
- Notebook computers
- Video graphics cards
- Monitors and flat panel displays
- 10/100/1000 ethernet
- SIM ports
- ATM interfaces

MECHANICAL CHARACTERISTICS

- JEDEC SOT23-6L package
- Molding compound flammability rating: UL 94V-0
- Quantity per reel: 3, 000pcs
- Lead finish: lead free

Reference News



ABSOLUTE MAXIMUM RATINGS (TA=25℃, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak pulse power dissipation on 8/20µs waveform	P _{PP}	100	W
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	+/- 20 +/-20	kV
Lead soldering temperature	T∟	260 (10 sec.)	$^{\circ}$
Operating junction temperature range	TJ	-55 to +125	$^{\circ}$
Storage temperature range	Тѕтс	-55 to +150	$^{\circ}$



ELECTRICAL CHARACTERISTICS (TA=25°C)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse working voltage	VRWM				5.0	V
Reverse breakdown voltage	V _{BR}	h=1mA	6.0			V
Reverse leakage current	l R	V _{RWM} =5V			1	μA
Forward voltage	VF	ե=10mA		0.8	1.0	V
Clamping voltage	Vc	I _{PP} =1A, t _P =8/20μs		9.5	11	V
(I/O pin to Ground)	Vc	IPP=5A, tP=8/20μs		12.5	15	
Junction capacitance	pacitance C _J	V _{RWM} =0V, f=1MHz Any I/O pin to Ground		0.65	0.8	pF
		V _{RWM} =0V, f=1MHz Between I/O pins		0.3	0.5	

RATINGS AND V-I CHARACTERISTICS CURVES (T_A=25°C, unless otherwise noted)

FIG.1:V- I curve characteristics (Uni-directional)

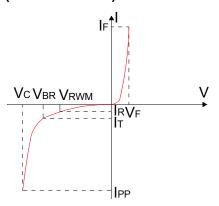


FIG.3: Pulse derating curve

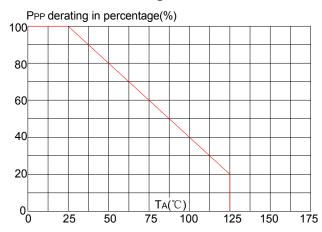


FIG.2: Pulse waveform (8/20µs)

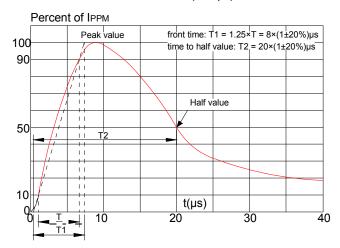
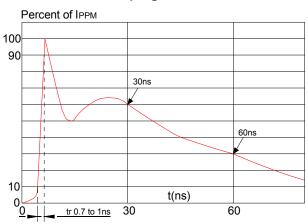
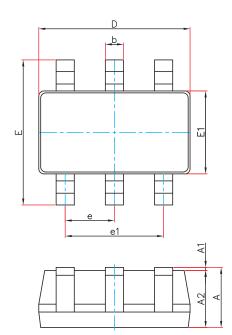


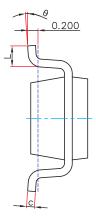
FIG.4: ESD clamping (20kV contact)





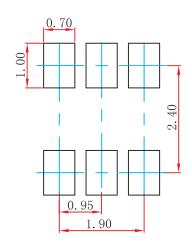
PACKAGEMECHANICALDATA





Symbol	Dimensions In Millimeters		Dimensions In Inches		
Syllibol	Min.	Max.	Min.	Max.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
E	2.650	2.950	0.104	0.116	
е	0.950(BSC)	0.037((BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters. 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

Order information

Orderable Device	Package	Packing Option
AZC099-04S-MS	SOT-23-6	3000PCS



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